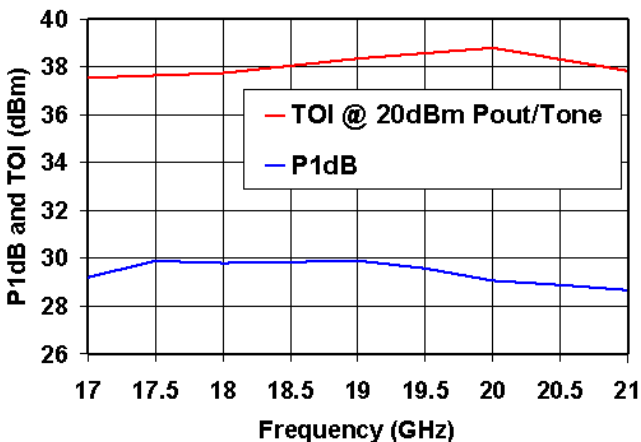
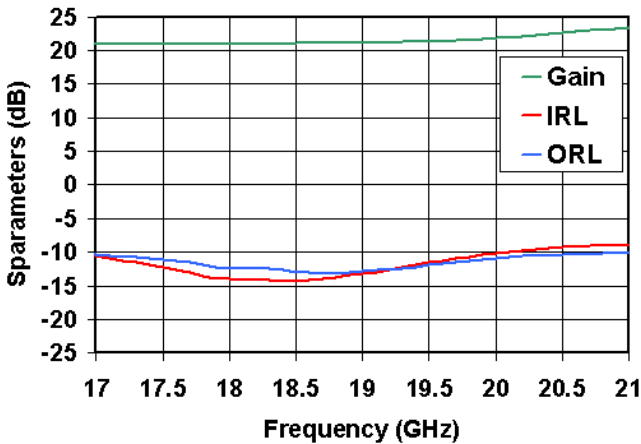


**17-21 GHz High Output TOI Packaged Amplifier**



**Measured Fixtured Data**

Bias Conditions:  $V_d = 6V$ ,  $I_d = 825mA$



**Key Features**

- Frequency Range: 17 - 21 GHz
- 38 dBm Nominal Output TOI
- 21 dB Nominal Gain
- 29 dBm Nominal P1dB
- 12 dB Nominal Return Loss
- Bias 6 V @ 825 mA
- 4 x 4 QFN with 20 leads
- Package Dimensions 4.0 x 4.0 x 1.2 mm

**Primary Applications**

- Point-to-Point Radio
- Point-to-Multipoint Communications
- K Band Sat-Com

**Product Description**

The TriQuint TGA4530-SM is a packaged High Power Amplifier for 17–21 GHz applications. The part is designed using using TriQuint’s power pHEMT production process.

The TGA4530-SM nominally provides 29 dBm saturated output power at the 1 dB compression gain and 38 dBm TOI for bias of 6 V, 825 mA. The typical gain is 21dB.

The TGA4530-SM is a QFN 4x4mm surface mount package. It is ideally suited for low cost emerging markets such as Point-to-Point Radio, Point-to-Multi Point Communications, and K-band Satellite Communications.

Evaluation Boards are available upon request.

Lead-Free & RoHS compliant

*Datasheet subject to change without notice.*

**TABLE I**  
**ABSOLUTE MAXIMUM RATINGS <sup>1/</sup>**

SYMBOL	PARAMETER	VALUE	NOTES
V <sub>d</sub>	Positive Supply Voltage	8 V	
V <sub>g</sub>	Negative Supply Voltage Range	-5 TO 0 V	
I <sub>d</sub>	Positive Supply Current	1.75 A	
I <sub>g</sub>	Negative Supply Current	35 mA	
P <sub>IN</sub>	Input Continuous Wave Power	26 dBm	
P <sub>D</sub>	Power Dissipation	14 W	
T <sub>channel</sub>	Channel Temperature	200 °C	<sup>2/</sup>
	Mounting Temperature (30 Seconds)	260 °C	
	Storage Temperature	-65 to 150 °C	

<sup>1/</sup> These ratings represent the maximum operable values for this device. Stresses beyond those listed under “Absolute Maximum Ratings” may cause permanent damage to the device and / or affect device lifetime. These are stress ratings only, and functional operation of the device at these conditions is not implied.

<sup>2/</sup> Combinations of supply voltage, supply current, input power, and output power shall not exceed P<sub>D</sub>.

**TABLE II**  
**ELECTRICAL CHARACTERISTICS**  
 (T<sub>a</sub> = 25 °C Nominal)

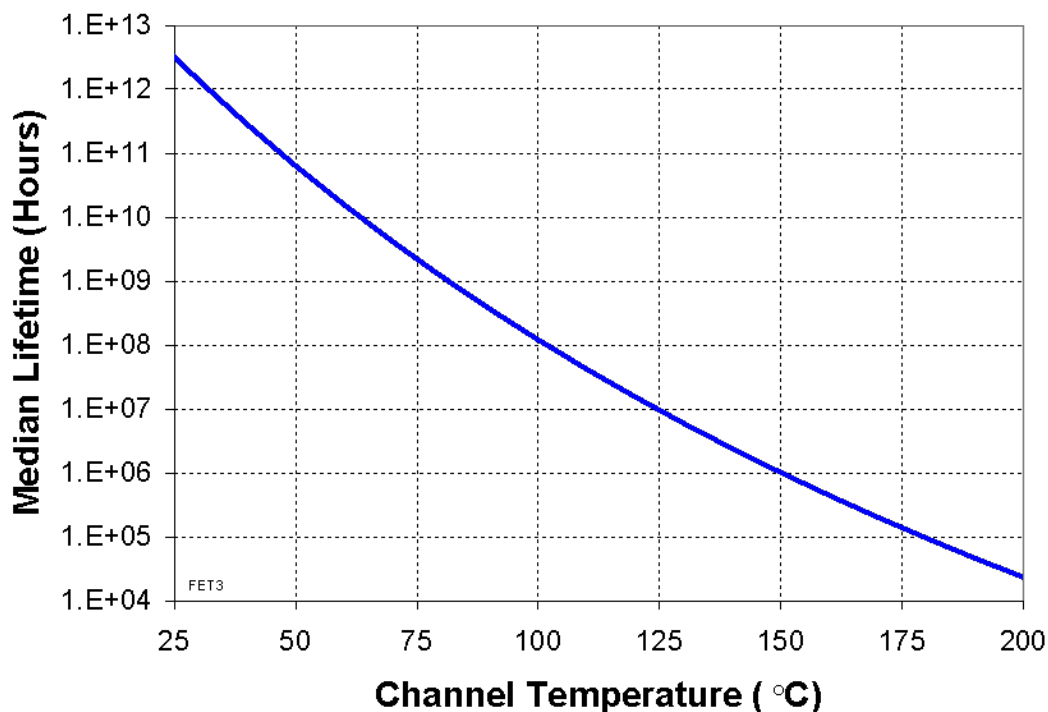
PARAMETER	TYPICAL	UNITS
Frequency Range	17 - 21	GHz
Drain Voltage, V <sub>d</sub>	6	V
Drain Current, I <sub>d</sub>	825	mA
Gate Voltage Typical, V <sub>g</sub>	-0.5	V
Small Signal Gain, S <sub>21</sub>	21	dB
Input Return Loss, S <sub>11</sub>	12	dB
Output Return Loss, S <sub>22</sub>	12	dB
Reverse Isolation, S <sub>12</sub>	55	dB
Saturated Output Power @ 16 dBm Pin, P <sub>sat</sub>	31	dBm
Output Power @ 1dB Gain Compression, P <sub>1dB</sub>	29	dBm
Output Third Order Intercepted Point	38	dBm
Small Signal Gain Temperature Coefficient	-0.03	dB/°C

**TABLE III  
THERMAL INFORMATION**

PARAMETER	TEST CONDITIONS	Tchannel (°C)	$\theta_{JC}$ (°C/W)	Tm (HRS)
$\theta_{JC}$ Thermal Resistance (channel to backside of package)	Vd = 6 V Id = 825 mA PD = 4.95 W Small Signal Tbase = 70°C	143	14.8	1.8E+6
$\theta_{JC}$ Thermal Resistance (channel to backside of package)	Vd = 6 V Id = 970 mA @ Psat PD = 4.4 W Pout = 1.4 W (RF) Tbase = 70°C	135	14.8	3.8E+6

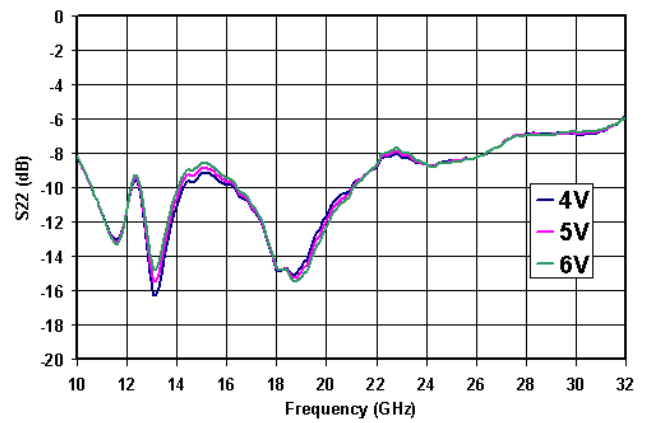
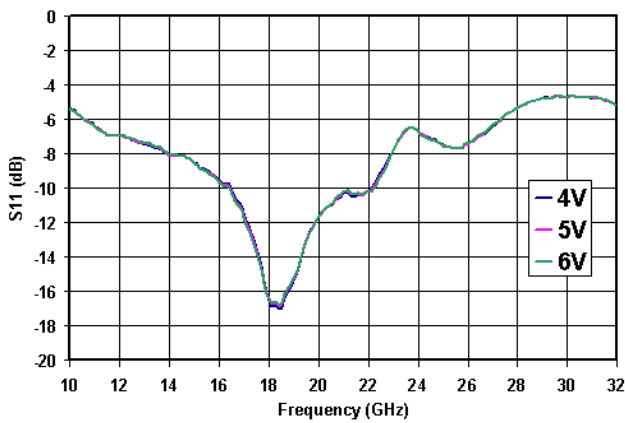
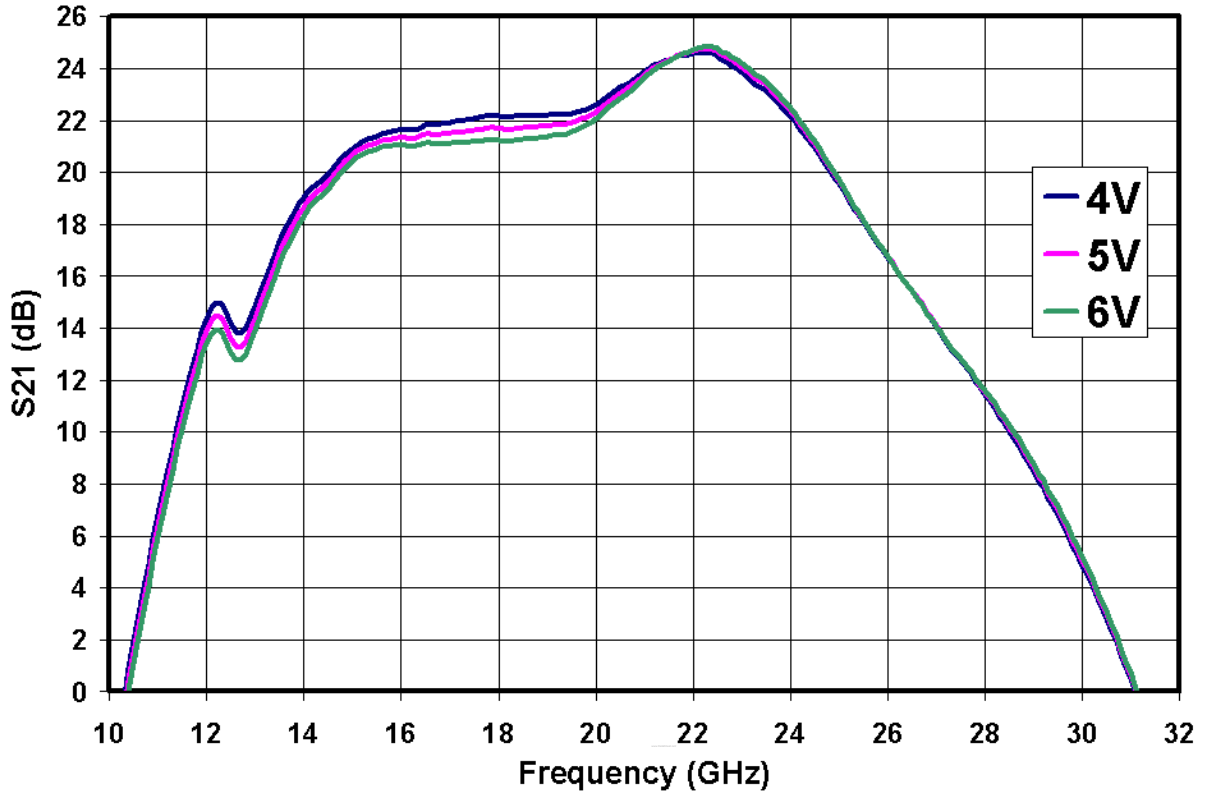
Note: Backside of package is the 70°C baseplate temperature. Thermal transfer is from the backside of the package through the board. The board must be designed to assure adequate thermal transfer from the package. Worst case condition is with no RF applied, 100% of DC power is dissipated.

**Median Lifetime (Tm) vs. Channel Temperature**



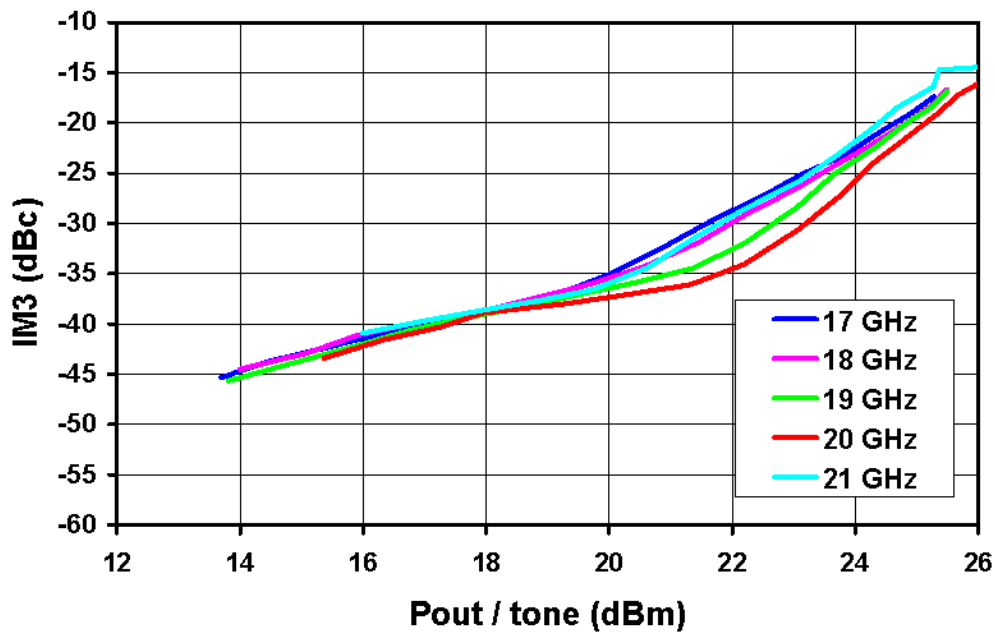
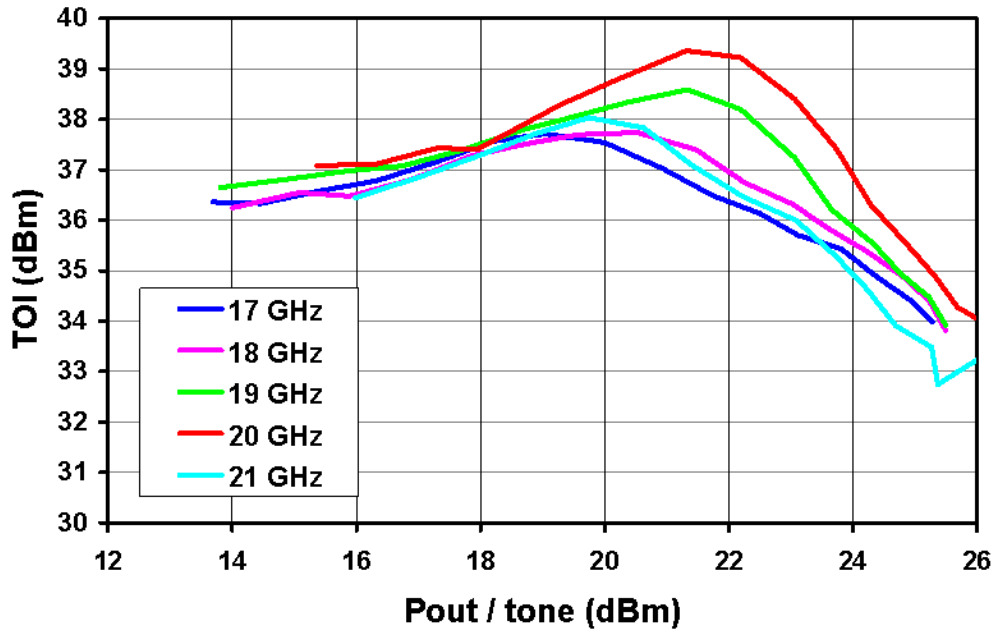
**Measured Data**

Vd = 4- 6V, Idq = 825mA  
Vg = -0.5 V (typ.)



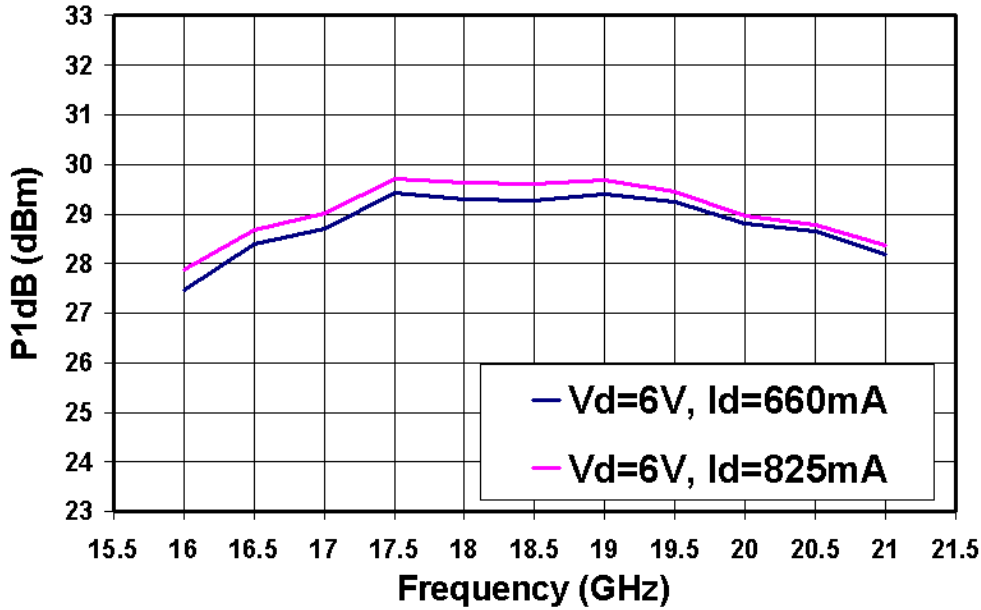
**Measured Data**

Vd = 6V, Id = 825mA  
Vg = -0.5 V (typ.)

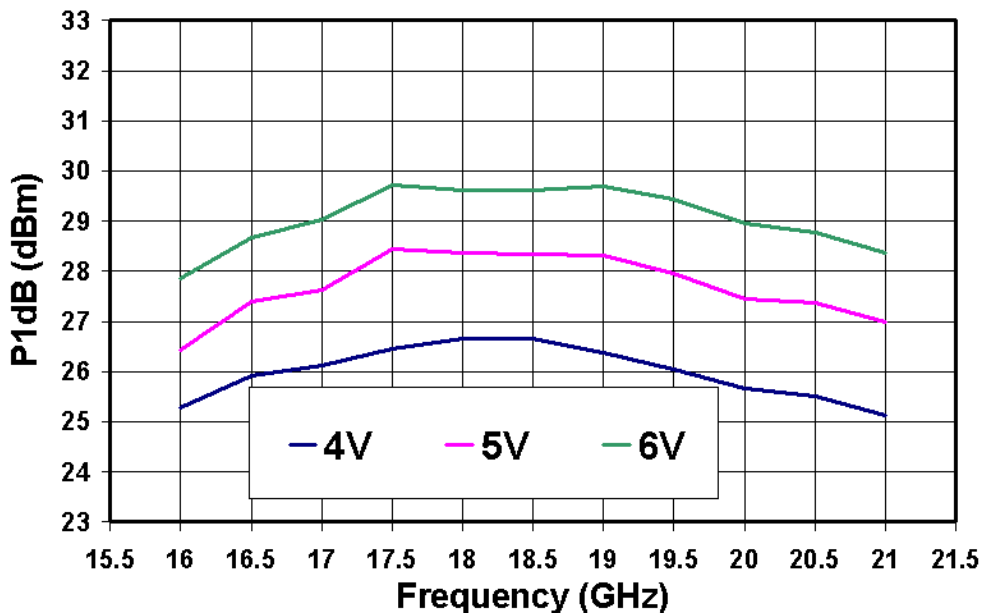


**Measured Data**

**Vd = 6V, Idq = 660, 825mA**  
**Vg = -0.5 V (typ.)**

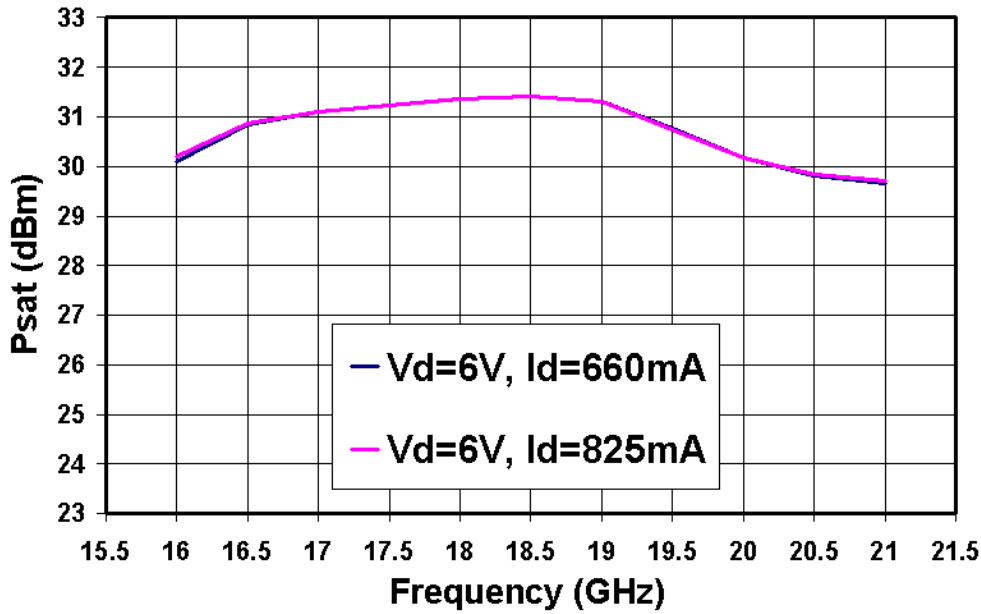


**Vd = 4-6V, Idq = 825mA**  
**Vg = -0.5 V (typ.)**

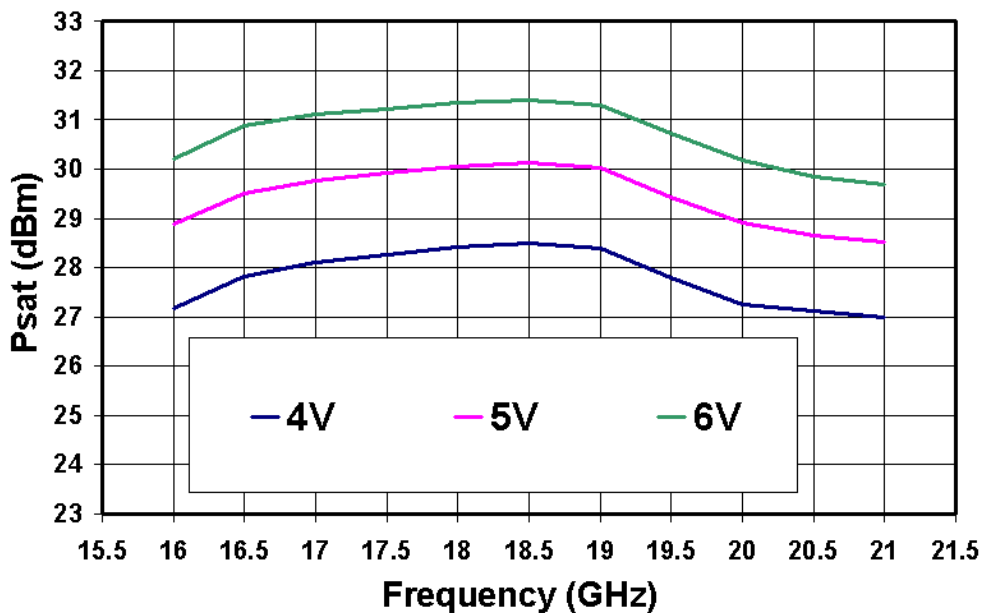


**Measured Data**

**Vd = 6V, Idq = 660, 825mA**  
**Vg = -0.5 V (typ.)**

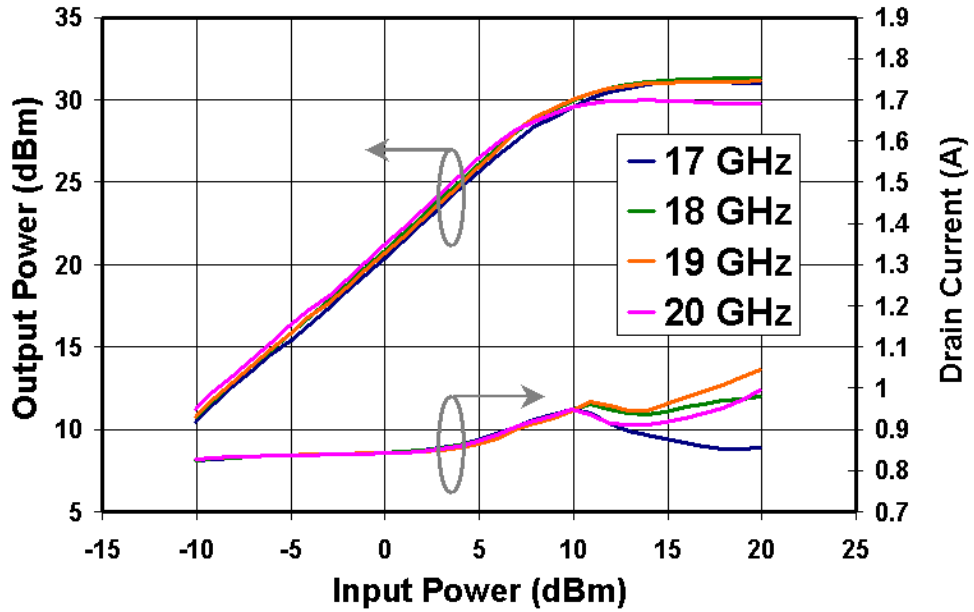


**Vd = 4-6V, Idq = 825mA**  
**Vg = -0.5 V (typ.)**



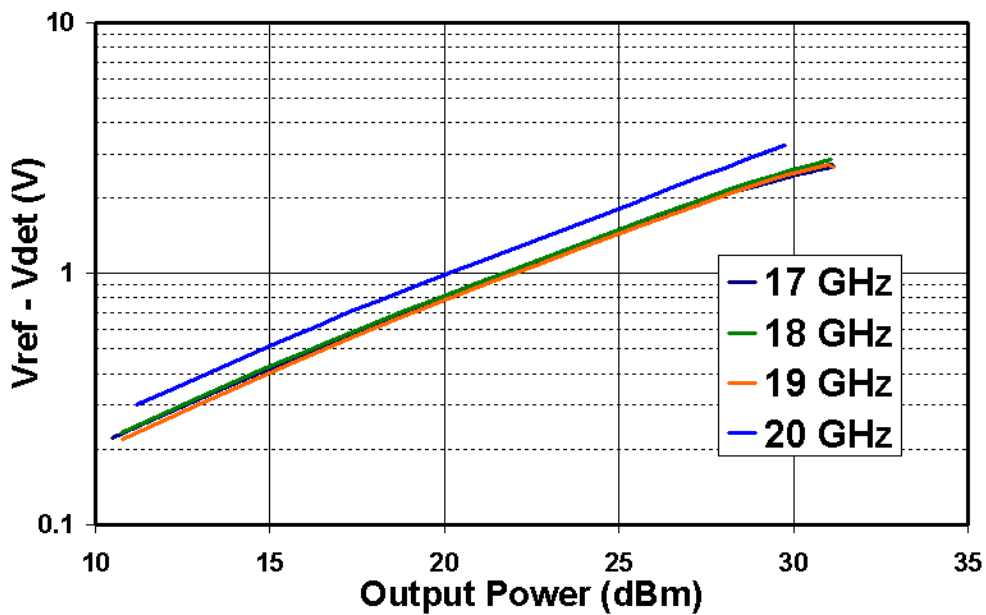
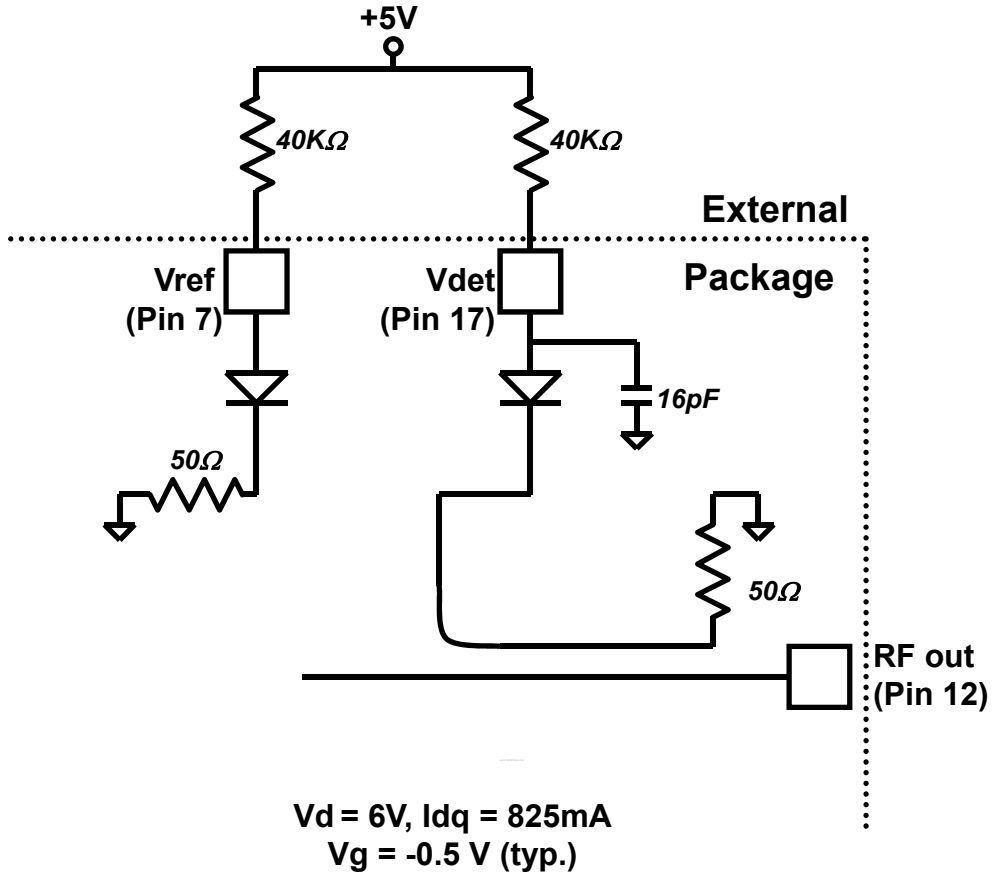
**Measured Data**

Vd = 6V, Idq = 825mA  
 Vg = -0.5 V (typ.)

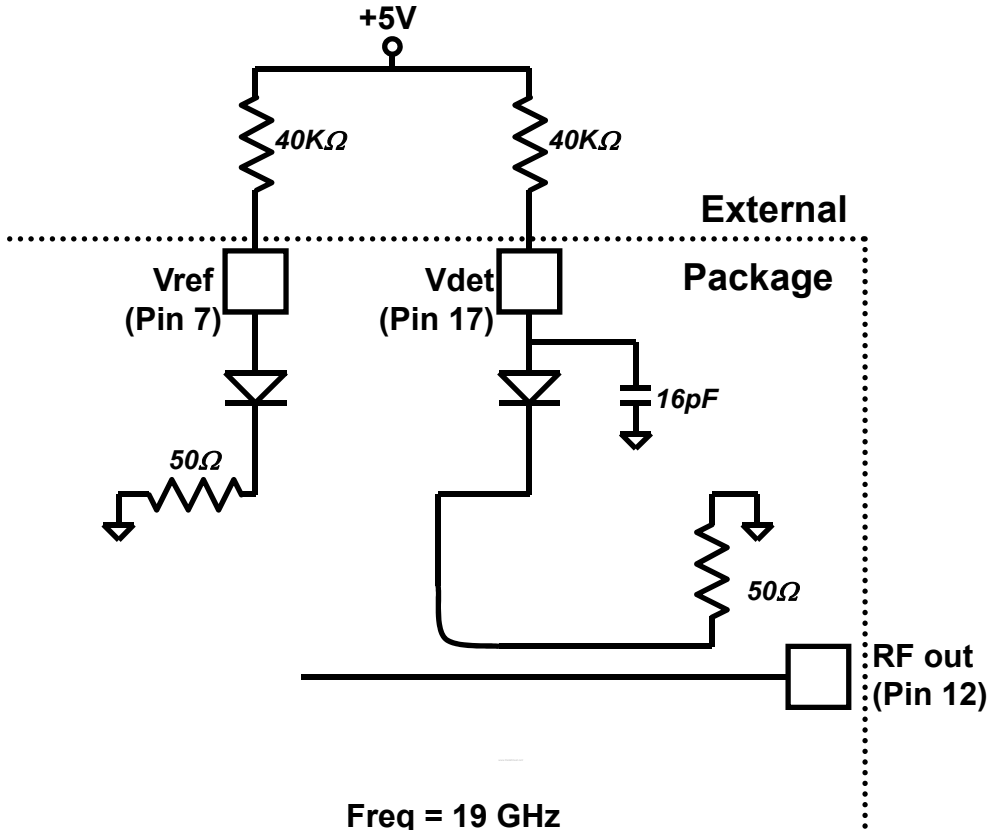




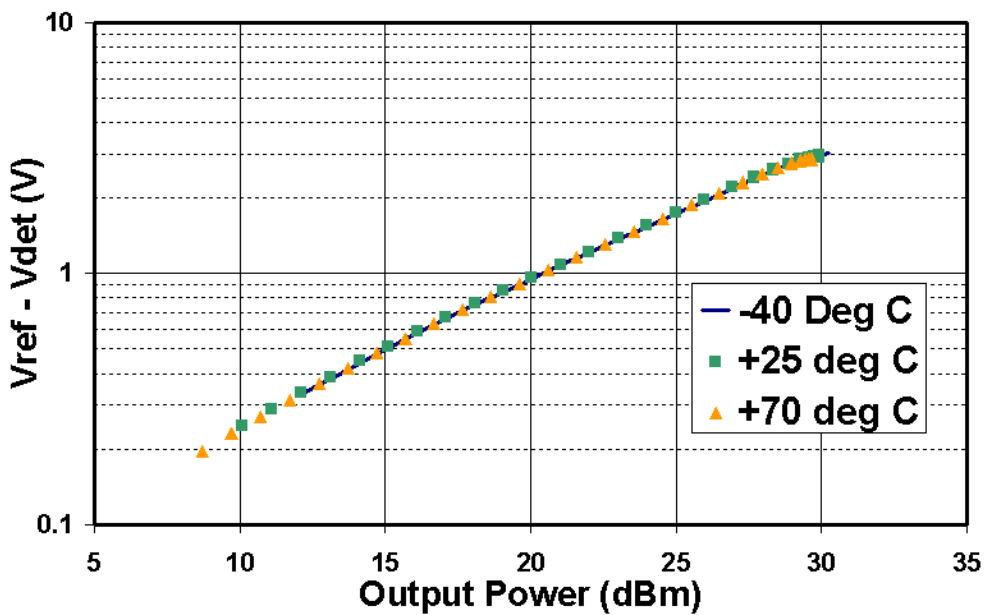
**Power Detector**

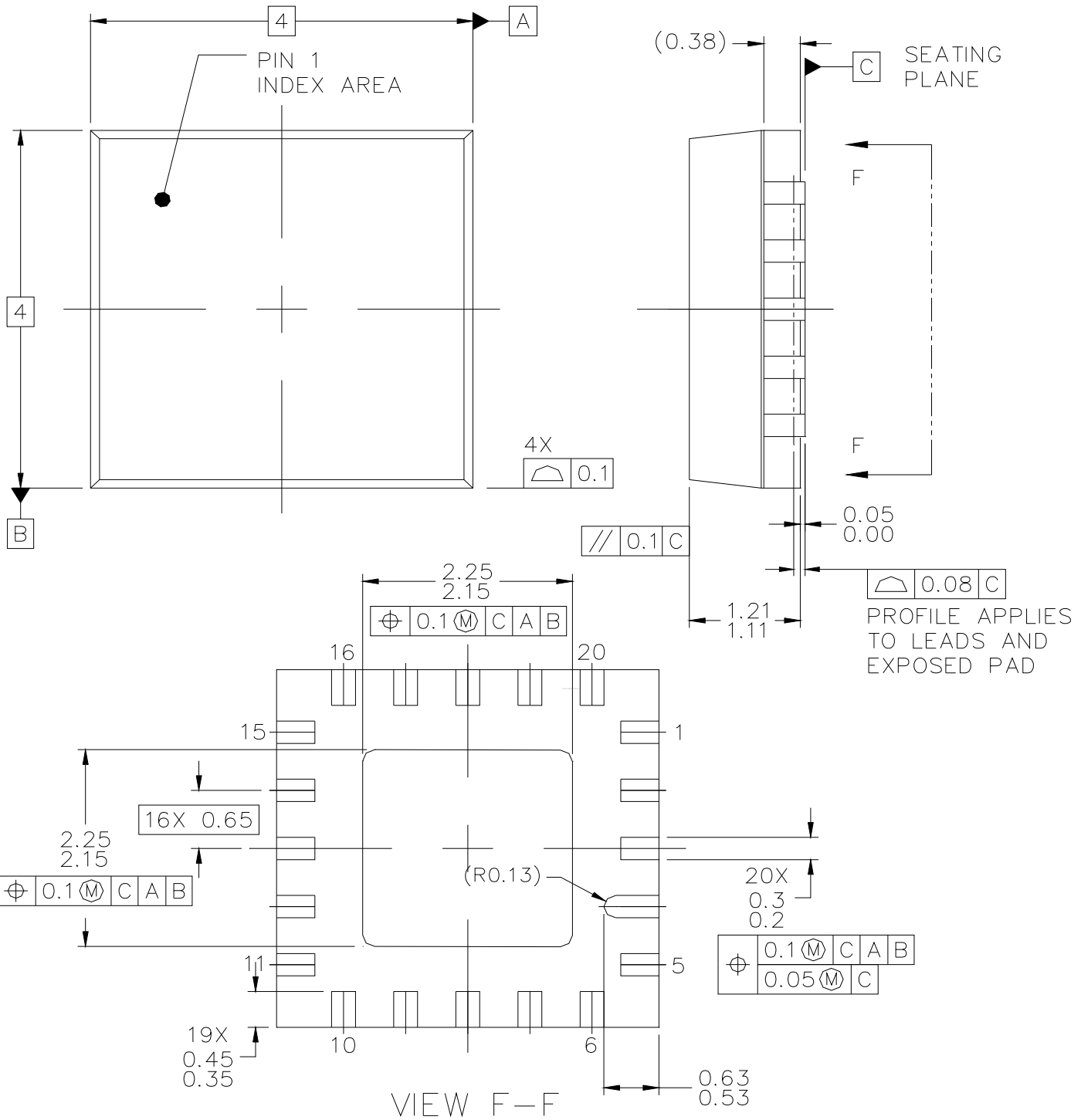


**Power Detector**



Freq = 19 GHz  
 Vd = 6V, Idq = 825mA  
 Vg = -0.5 V (typ.)



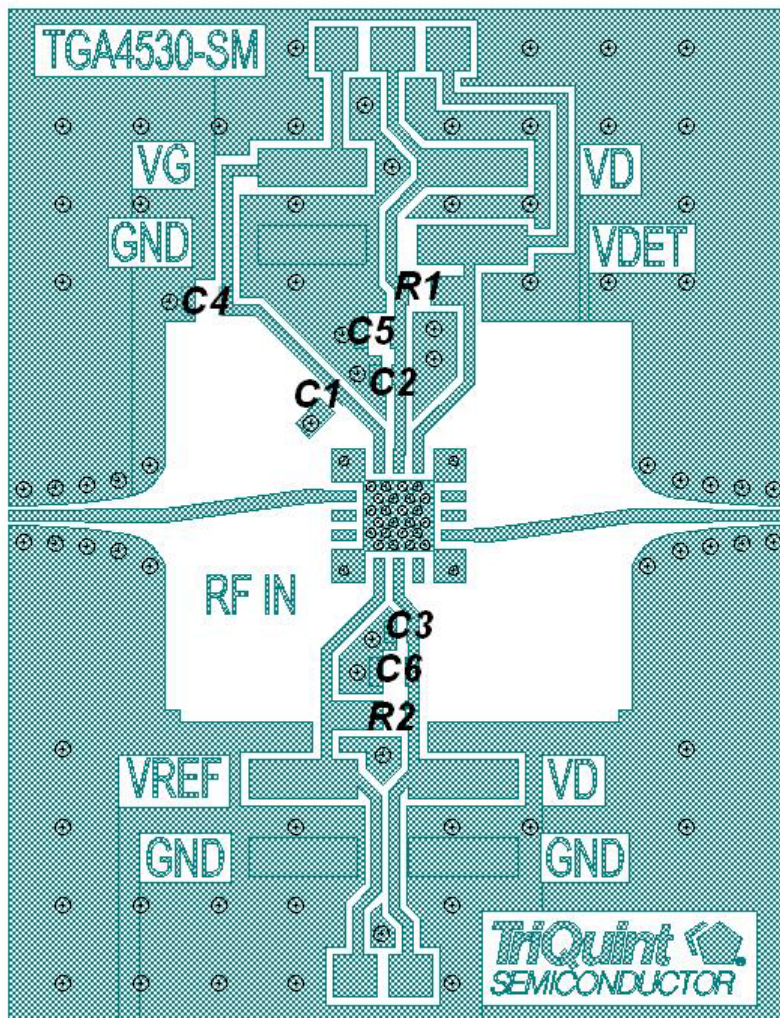


Pin	Description
1, 5, 6, 10, 11, 15, 16, 20, 21	GND
3, 4, 9, 13, 14	NC
2	RF Input
19	Vg

Pin	Description
8 and 18	Vd
12	RF Output
17	Vdet
7	Vref

**GaAs MMIC devices are susceptible to damage from Electrostatic Discharge. Proper precautions should be observed during handling, assembly and test.**

**Recommended Evaluation Board Layout Assembly \***



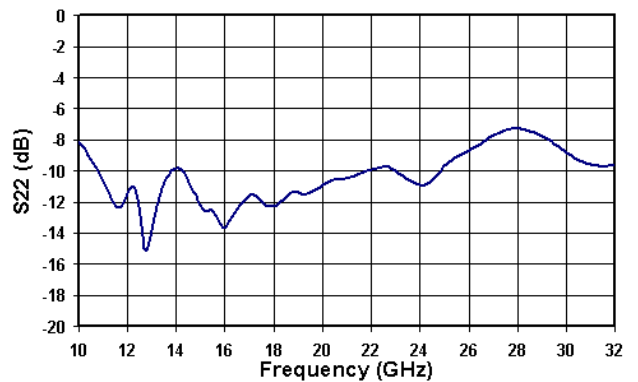
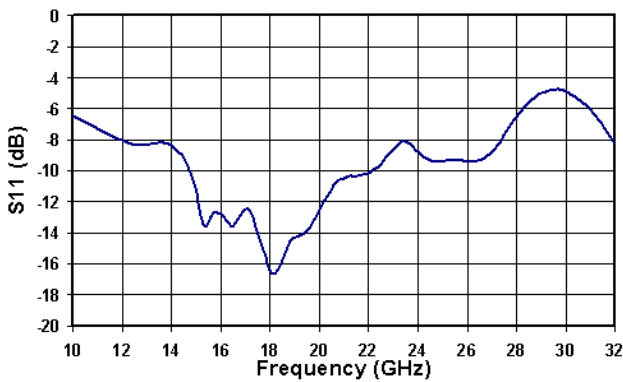
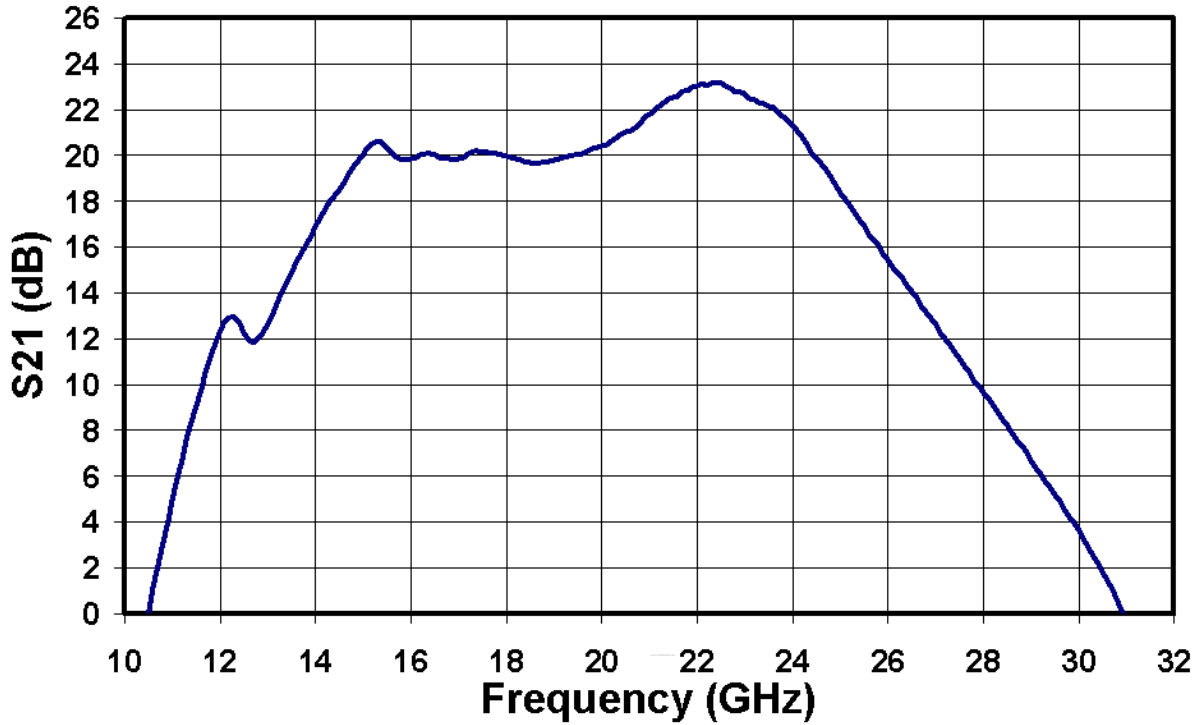
Designator	Component
C1,C2,C3	100pF Capacitor
C4,C5,C6	1uF Capacitor
R1,R2	40.2kOhm Resistor

\* PCB is RO4003 8 mil thickness, 0.5 oz standard copper cladding, with Er = 3.38.

**GaAs MMIC devices are susceptible to damage from Electrostatic Discharge. Proper precautions should be observed during handling, assembly and test.**

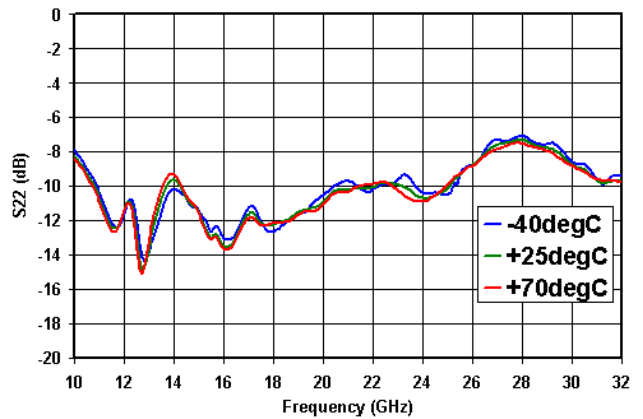
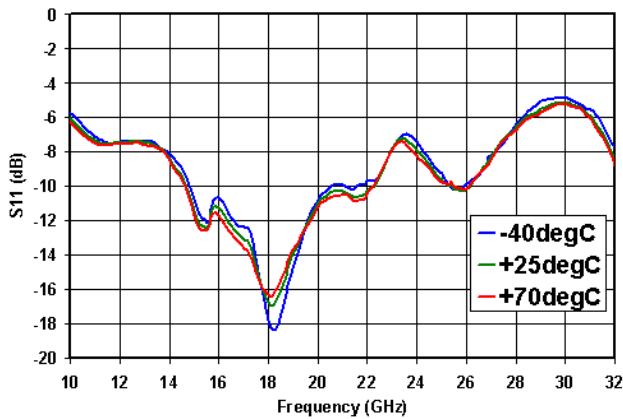
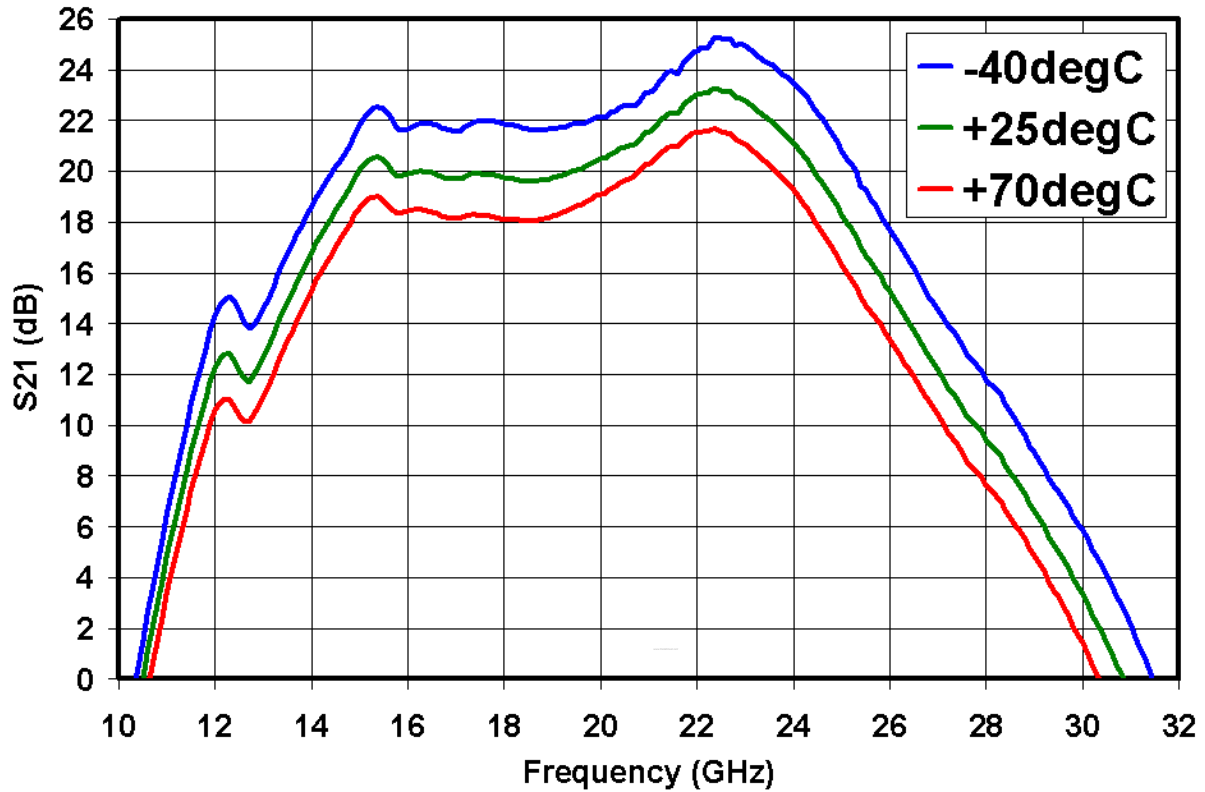
**Measured Data - Evaluation Board**  
Data includes connector and board losses

Vd = 6V, Id = 825mA  
Vg = -0.5 V (typ.)



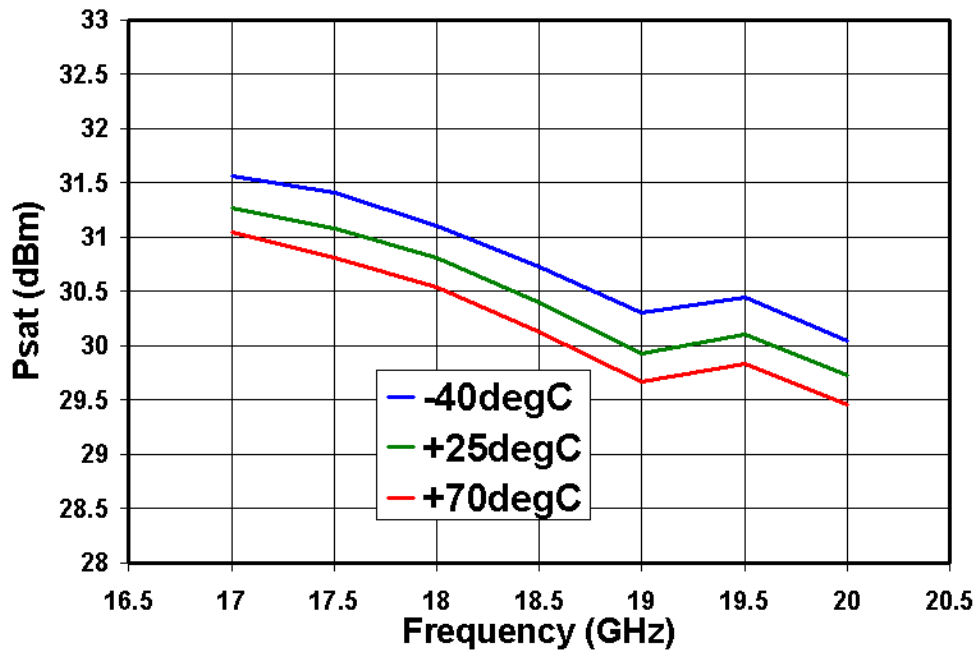
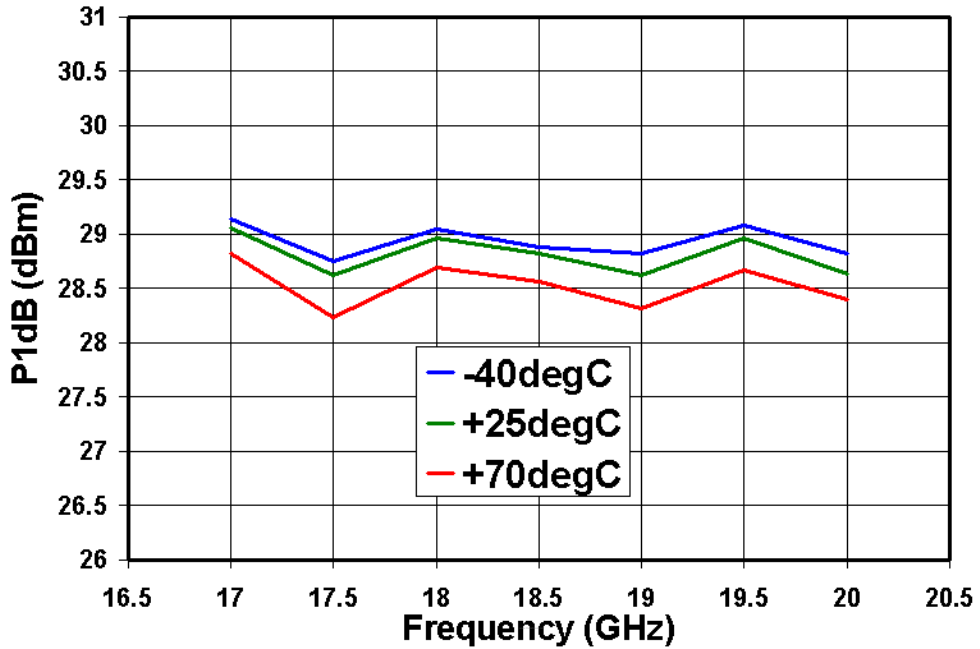
**Measured Data - Evaluation Board**  
Data includes connector and board losses

Vd = 6V, Id = 825mA  
Vg = -0.5 V (typ.)



**Measured Data - Evaluation Board**  
**Data includes connector and board losses**

Vd = 6V, Idq = 825mA  
 Vg = -0.5 V (typ.)



## Recommended Surface Mount Package Assembly

Proper ESD precautions must be followed while handling packages.

TriQuint recommends using a conductive solder paste for attachment. Follow solder paste and reflow oven vendors' recommendations when developing a solder reflow profile. Typical solder reflow profiles are listed in the table below.

Hand soldering is not recommended. Solder paste can be applied using a stencil printer or dot placement. The volume of solder paste depends on PCB and component layout and should be well controlled to ensure consistent mechanical and electrical performance.

Solder attach process requires the use of no clean flux.

### Typical Solder Reflow Profiles

Reflow Profile	SnPb	Pb Free
Ramp-up Rate	3 °C/sec	3 °C/sec
Activation Time and Temperature	60 – 120 sec @ 140 – 160 °C	60 – 180 sec @ 150 – 200 °C
Time above Melting Point	60 – 150 sec	60 – 150 sec
Max Peak Temperature	240 °C	260 °C
Time within 5 °C of Peak Temperature	10 – 20 sec	10 – 20 sec
Ramp-down Rate	4 – 6 °C/sec	4 – 6 °C/sec

### Ordering Information

Part	Package Style
TGA4530-SM	QFN 4x4 Surface Mount